

Description

The 8205A-HXY uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a Battery protection or in other Switching application.

General Features

 $V_{DS} = 20V, I_D = 6A$

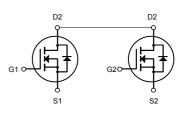
 $R_{DS(ON)} < 25m\Omega @ V_{GS}=4.5V$

Application

Battery protection Load switch Power management



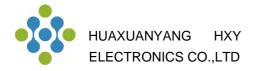




Dual N-Channel MOSFET

Package Marking and Ordering Information

| Product ID | | Pack | Marking | | Qty(PCS) | |
|-----------------|---|--|--------------------|-------------|-------------|-------|
| 3205A-HXY | | SOT23-6L | 8205 XXX YY | YY | 3000 | |
| Absolute Max | imum R | atings@Tj=25° | °C(unless otherwis | e specified | d) | |
| Symbol | | Parameter | | Rating | | Units |
| V _{DS} | Drain-S | Drain-Source Voltage | | | 20 | |
| V _{GS} | Gate-S | Gate-Source Voltage | | | <u>+</u> 10 | |
| Id@Ta=25°C | Drain C | Drain Current, V _{GS} @ 4.5V ³ | | | 6 | |
| Ідм | Pulsed | Pulsed Drain Current ¹ | | | 25 | |
| P₀@T₄=25℃ | Total P | Total Power Dissipation | | | 1.25 | |
| Тѕтс | Storage | Storage Temperature Range | | | -55 to 150 | |
| TJ | Operat | Operating Junction Temperature Range | | | -55 to 150 | |
| Rthj-a | Maximum Thermal Resistance, Junction- ambient ³ | | | 100 | | °C/W |



Electrical Characteristics (T_A=25[°]C unless otherwise noted)

| Parameter | Symbol | Condition | Min | Тур | Max | Unit |
|------------------------------------|---------------------|--|-----|-----|------|------|
| Off Characteristics | | | | | | • |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V I _D =250µA | 20 | 21 | - | V |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =19.5V,V _{GS} =0V | - | - | 1 | μA |
| Gate-Body Leakage Current | I _{GSS} | V_{GS} =±10V, V_{DS} =0V | - | - | ±100 | nA |
| On Characteristics (Note 3) | | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | $V_{DS}=V_{GS}$, $I_{D}=250\mu A$ | 0.5 | 0.7 | 1.2 | V |
| Drain October Or Otata Davistance | R _{DS(ON)} | V _{GS} =4.5V, I _D =4A | - | 22 | 25 | mΩ |
| Drain-Source On-State Resistance | | V _{GS} =2.5V, I _D =3A | - | 26 | 31 | mΩ |
| Forward Transconductance | g fs | V _{DS} =5V,I _D =4A | - | 10 | - | S |
| Dynamic Characteristics (Note4) | | | | | | |
| Input Capacitance | C _{lss} | | - | 600 | - | PF |
| Output Capacitance | C _{oss} | V _{DS} =8V,V _{GS} =0V, F=1.0MHz | - | 330 | - | PF |
| Reverse Transfer Capacitance | C _{rss} | F=1.0MHZ | - | 140 | - | PF |
| Switching Characteristics (Note 4) | | | | | | • |
| Turn-on Delay Time | t _{d(on)} | | - | 18 | - | nS |
| Turn-on Rise Time | tr | V _{DD} =10V,I _D =1A | - | 5 | - | nS |
| Turn-Off Delay Time | t _{d(off)} | V_{GS} =4V, R_{GEN} =10 Ω | - | 43 | - | nS |
| Turn-Off Fall Time | t _f | | - | 20 | - | nS |
| Total Gate Charge | Qg | | - | 11 | - | nC |
| Gate-Source Charge | Q _{gs} | V_{DS} =10V,I _D =4A, | - | 2.3 | - | nC |
| Gate-Drain Charge | Q _{gd} | V _{GS} =4.5V | - | 2.5 | - | nC |
| Drain-Source Diode Characteristics | | | | | • | |
| Diode Forward Voltage (Note 3) | V _{SD} | V _{GS} =0V,I _S =2A | - | 0.8 | 1.2 | V |
| Diode Forward Current (Note 2) | Is | | - | - | 2 | Α |

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, $t \le 10$ sec.

3. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.

4. Guaranteed by design, not subject to production



Typical Electrical and Thermal Characteristics

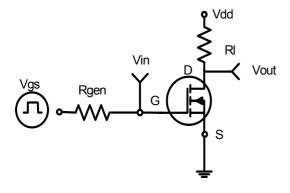
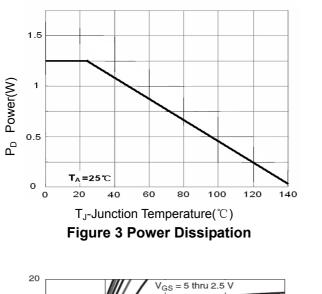
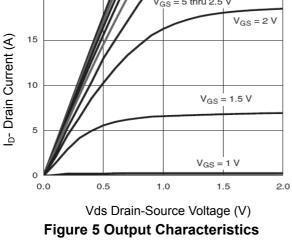


Figure 1:Switching Test Circuit





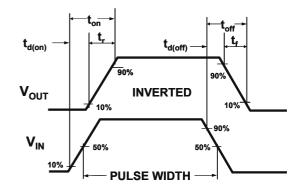
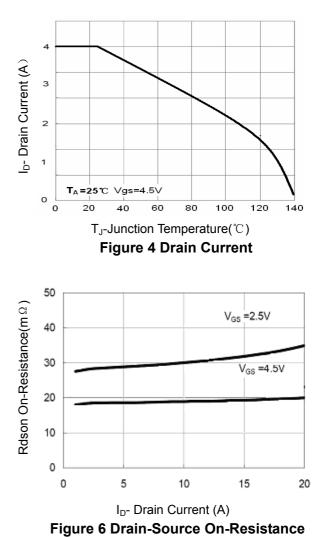
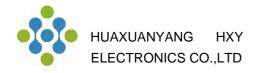
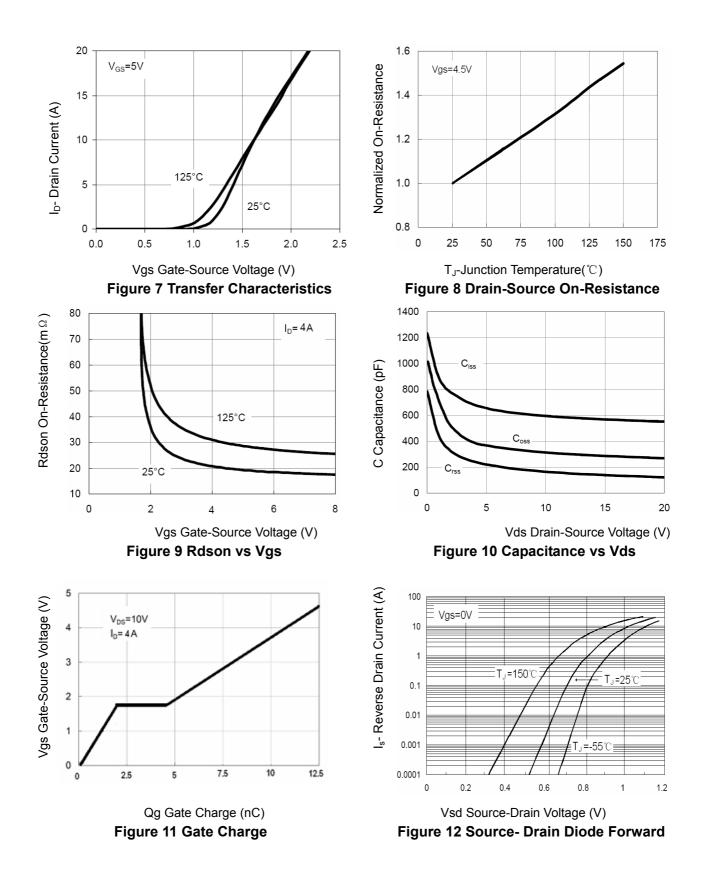


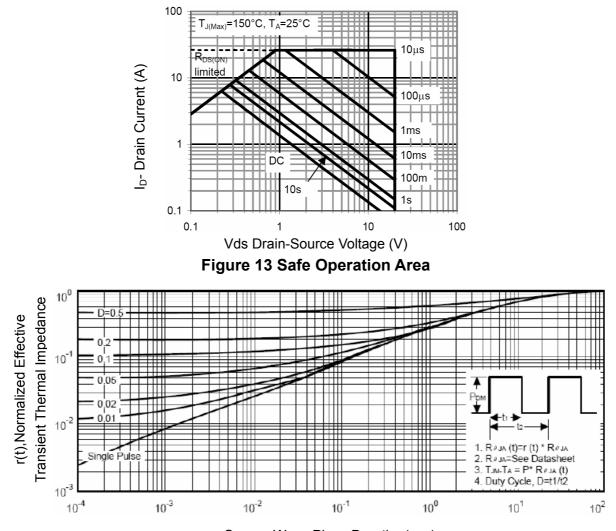
Figure 2:Switching Waveforms







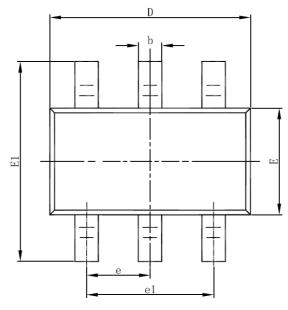


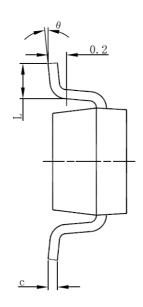


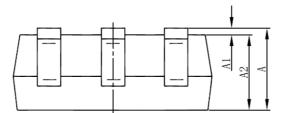
Square Wave Pluse Duration(sec) Figure 14 Normalized Maximum Transient Thermal Impedance



SOT23-6L Package Information







| Symbol | Dimensions Ir | n Millimeters | Dimensions In Inches | | |
|--------|---------------|---------------|----------------------|-------|--|
| | Min | Max | Min | Max | |
| А | 1.050 | 1.250 | 0.041 | 0.049 | |
| A1 | 0.000 | 0.100 | 0.000 | 0.004 | |
| A2 | 1.050 | 1.150 | 0.041 | 0.045 | |
| b | 0.300 | 0.500 | 0.012 | 0.020 | |
| С | 0.100 | 0.200 | 0.004 | 0.008 | |
| D | 2.820 | 3.020 | 0.111 | 0.119 | |
| Е | 1.500 | 1.700 | 0.059 | 0.067 | |
| E1 | 2.650 | 2.950 | 0.104 | 0.116 | |
| е | 0.950 | (BSC) | 0.037(BSC) | | |
| e1 | 1.800 | 2.000 | 0.071 | 0.079 | |
| L | 0.300 | 0.600 | 0.012 | 0.024 | |
| θ | 0° | 8° | 0° | 8° | |



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